

**isc Silicon NPN RF Transistor**
**2SC5089**
**DESCRIPTION**

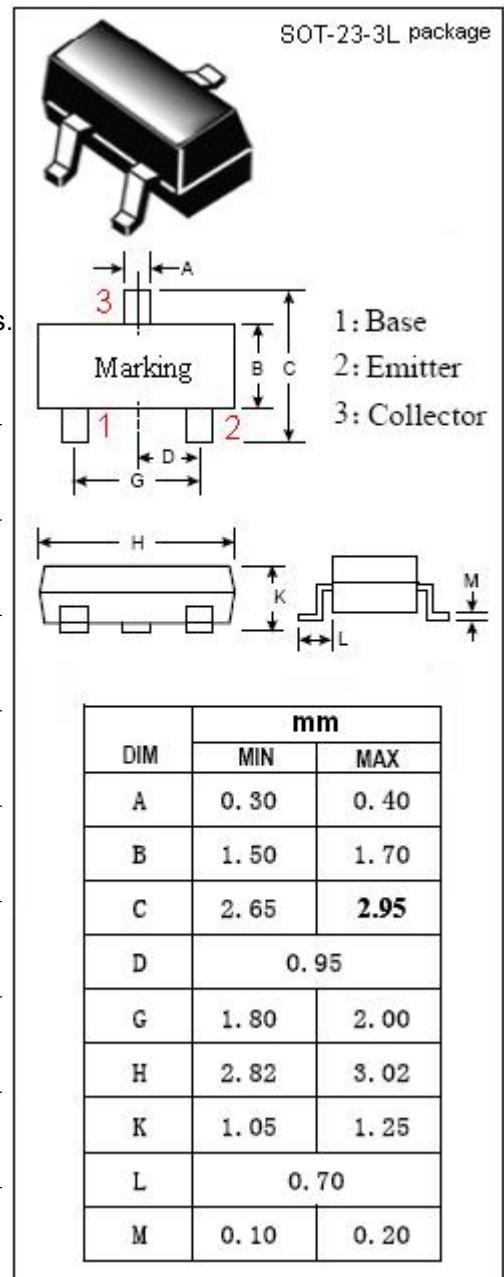
- High Gain Bandwidth Product  
 $f_T = 10 \text{ GHz TYP.}$
- High Gain, Low Noise Figure  
 $|S_{21e}|^2 = 13 \text{ dB TYP., NF} = 1.1 \text{ dB TYP @ } f = 1 \text{ GHz}$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Designed for VHF~UHF band low noise amplifier applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	20	V
$V_{CEO}$	Collector-Emitter Voltage	10	V
$V_{EBO}$	Emitter-Base Voltage	1.5	V
$I_C$	Collector Current-Continuous	40	mA
$I_B$	Base Current-Continuous	20	mA
$P_C$	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	0.15	W
$T_J$	Junction Temperature	125	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~125	$^\circ\text{C}$



## isc Silicon NPN RF Transistor

2SC5089

## ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 10V; I <sub>E</sub> = 0			1	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 1V; I <sub>C</sub> = 0			1	μ A
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 20mA ; V <sub>CE</sub> = 8V	50		160	
S <sub>21e</sub>   <sup>2</sup>	Insertion Power Gain	I <sub>C</sub> = 20mA; V <sub>CE</sub> = 8V; f= 1GHz	10	13		dB
S <sub>21e</sub>   <sup>2</sup>	Insertion Power Gain	I <sub>C</sub> = 20mA; V <sub>CE</sub> = 8V; f= 2GHz		7		dB
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 20mA ; V <sub>CE</sub> = 8V	7	10		GHz
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V; f= 1.0MHz		0.7		pF
C <sub>re</sub>	Feedback Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V; f= 1.0MHz		0.5	0.95	pF
NF	Noise Figure	I <sub>C</sub> = 5mA ; V <sub>CE</sub> = 8V; f= 1GHz		1.1	2.5	dB
NF	Noise Figure	I <sub>C</sub> = 5mA ; V <sub>CE</sub> = 8V; f= 2GHz		1.7		dB

◆ h<sub>FE</sub> Classification

R	O
50-100	80-160

**NOTICE:**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.